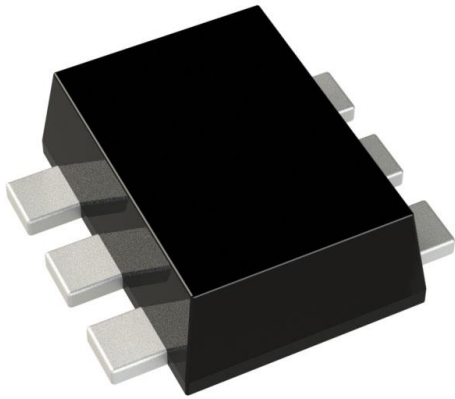


# DSS5240V-7 Datasheet

[www.digi-electronics.com](http://www.digi-electronics.com)



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	DSS5240V-7-DG
Manufacturer	<a href="#">Diodes Incorporated</a>
Manufacturer Product Number	DSS5240V-7
Description	TRANS PNP 40V 1.8A SOT563
Detailed Description	Bipolar (BJT) Transistor PNP 40 V 1.8 A 150MHz 600 mW Surface Mount SOT-563



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

DiGi is a global authorized distributor of electronic components.

## Purchase and inquiry

Manufacturer Product Number:

DSS5240V-7

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

40 V

Current - Collector Cutoff (Max):

100nA

Power - Max:

600 mW

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

SOT-563, SOT-666

Base Product Number:

DSS5240

Manufacturer:

Diodes Incorporated

Product Status:

Active

Current - Collector (Ic) (Max):

1.8 A

Vce Saturation (Max) @ Ib, Ic:

530mV @ 200mA, 2A

DC Current Gain (hFE) (Min) @ Ic, Vce:

300 @ 100mA, 5V

Frequency - Transition:

150MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-563

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99





DSS5240V

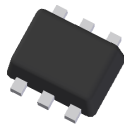
LOW  $V_{CE(SAT)}$  PNP SURFACE MOUNT TRANSISTOR

## Features

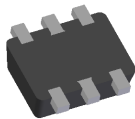
- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DSS4240V)
- Low Collector-Emitter Saturation Voltage,  $V_{CE(SAT)}$
- Surface Mount Package Suited for Automated Assembly
- Ultra-Small Surface Mount Package
- **Lead Free/RoHS Compliant (Note 1)**
- **"Green Device" (Note 2)**

## Mechanical Data

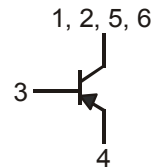
- Case: SOT-563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish — Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.003 grams (approximate)



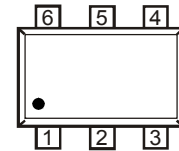
Top View



Bottom View



Device Schematic



Pin Out Configuration

## Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-40	V
Collector-Emitter Voltage	$V_{CEO}$	-40	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Collector Current - Continuous	$I_C$	-1.8	A
Peak Repetitive Collector Current (Note 3)	$I_{CRP}$	-2	A
Peak Pulse Collector Current	$I_{CM}$	-3	A
Base Current (DC)	$I_B$	-300	mA
Peak Base Current	$I_{BM}$	-1	A

## Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4) @ $T_A = 25^\circ\text{C}$	$P_D$	600	mW
Thermal Resistance, Junction to Ambient (Note 4) @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	208	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

- Notes:
1. No purposefully added lead.
  2. Diode's Inc.'s "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).
  3. Operated under pulse conditions: duty cycle  $\leq 20\%$ , pulse width  $t_p \leq 30\text{ms}$ .
  4. Device mounted on FR-4 PCB with minimum recommended pad layout.

**Electrical Characteristics** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-40	—	—	V	$I_C = -100\mu\text{A}, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 5)	$V_{(BR)CEO}$	-40	—	—	V	$I_C = -10\text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5	—	—	V	$I_E = -100\mu\text{A}, I_C = 0$
Collector Cutoff Current	$I_{CBO}$	—	—	-100 -50	nA $\mu\text{A}$	$V_{CB} = -40\text{V}, I_E = 0$ $V_{CB} = -40\text{V}, I_E = 0, T_A = 150^\circ\text{C}$
Collector Cutoff Current	$I_{CES}$	—	—	-100	nA	$V_{CE} = -40\text{V}, V_{BE} = 0$
Emitter Cutoff Current	$I_{EBO}$	—	—	-100	nA	$V_{EB} = -5\text{V}, I_C = 0$
<b>ON CHARACTERISTICS (Note 5)</b>						
DC Current Gain	$h_{FE}$	300	—	—	—	$V_{CE} = -5\text{V}, I_C = -1\text{mA}$
		300	—	800		$V_{CE} = -5\text{V}, I_C = -100\text{mA}$
		250	—	—		$V_{CE} = -5\text{V}, I_C = -500\text{mA}$
		160	—	—		$V_{CE} = -5\text{V}, I_C = -1\text{A}$
		50	—	—		$V_{CE} = -5\text{V}, I_C = -2\text{A}$
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	—	-120	mV	$I_C = -100\text{mA}, I_B = -1\text{mA}$
		—	—	-145		$I_C = -500\text{mA}, I_B = -50\text{mA}$
		—	—	-250		$I_C = -1\text{A}, I_B = -100\text{mA}$
		—	—	-530		$I_C = -2\text{A}, I_B = -200\text{mA}$
Collector-Emitter Saturation Resistance	$R_{CE(SAT)}$	—	—	250	m $\Omega$	$I_C = -1\text{A}, I_B = -100\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	—	—	-1.1	V	$I_C = -1\text{A}, I_B = -100\text{mA}$
Base-Emitter Turn On Voltage	$V_{BE(ON)}$	—	—	-1	V	$V_{CE} = -5\text{V}, I_C = -1\text{A}$
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Output Capacitance	$C_{obo}$	—	—	15	pF	$V_{CB} = -10\text{V}, f = 1.0\text{MHz}$
Current Gain-Bandwidth Product	$f_T$	150	—	—	MHz	$V_{CE} = -10\text{V}, I_C = -50\text{mA}, f = 100\text{MHz}$
<b>SWITCHING CHARACTERISTICS</b>						
Turn-On Time	$t_{on}$	—	60	—	ns	$V_{CC} = -10\text{V}$ $I_C = -1\text{A}, I_{B1} = I_{B2} = -50\text{mA}$
Delay Time	$t_d$	—	20	—	ns	
Rise Time	$t_r$	—	40	—	ns	
Turn-Off Time	$t_{off}$	—	167	—	ns	
Storage Time	$t_s$	—	140	—	ns	
Fall Time	$t_f$	—	27	—	ns	

Notes: 5. Measured under pulsed conditions. Pulse width = 300 $\mu\text{s}$ . Duty cycle  $\leq 2\%$ .

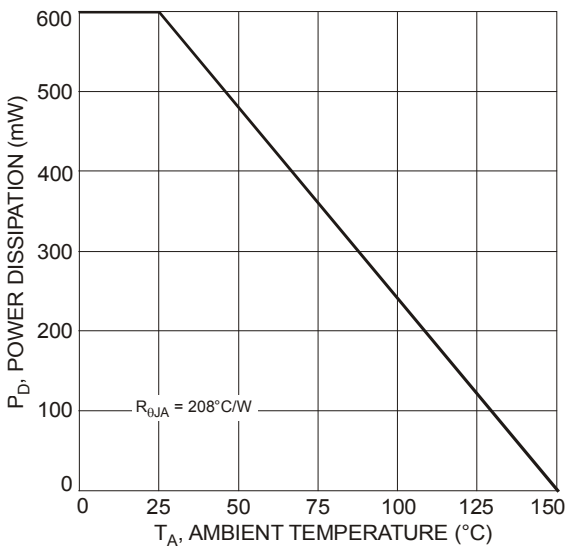


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 4)

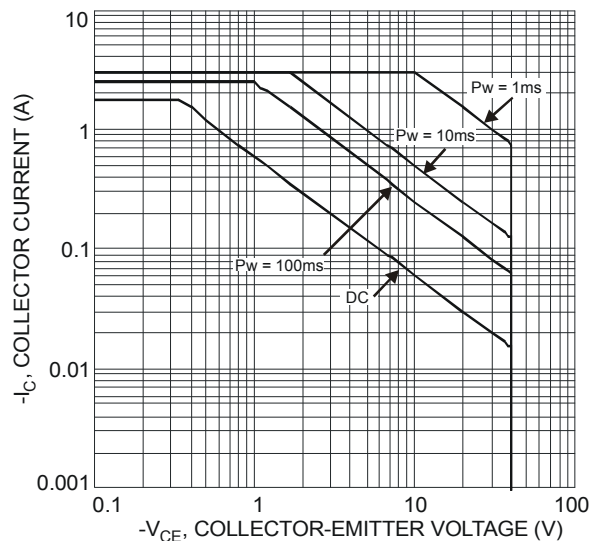


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage (Note 4)



DSS5240V

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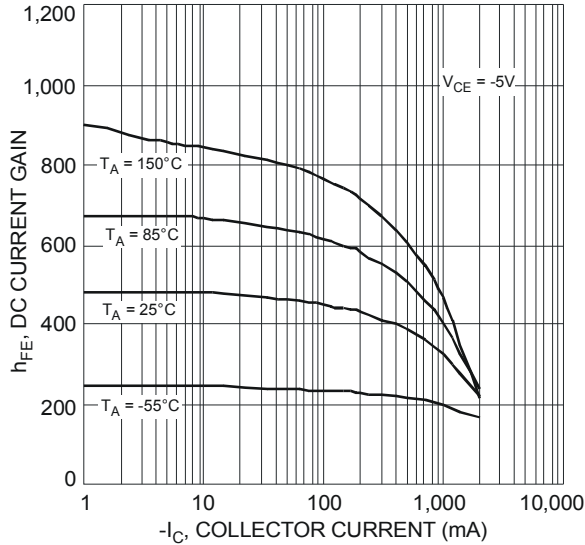


Fig. 3 Typical DC Current Gain vs. Collector Current

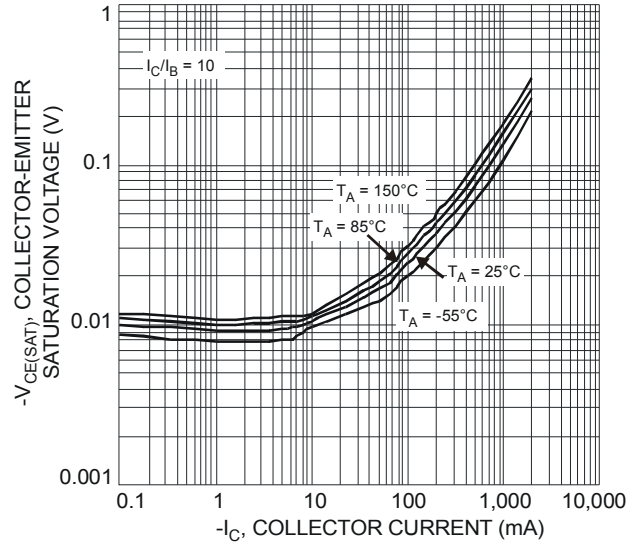


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

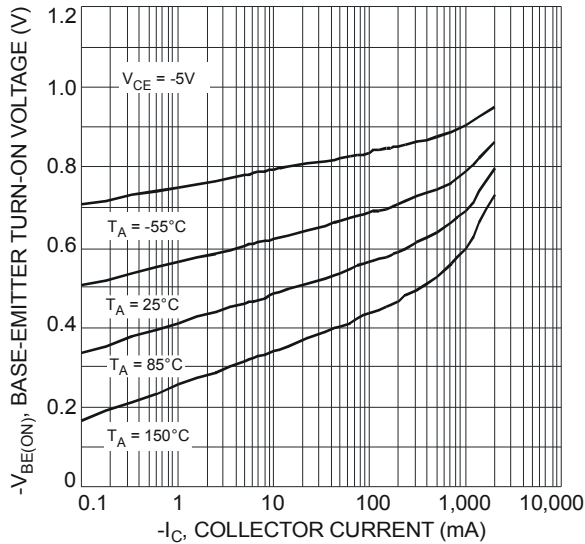


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

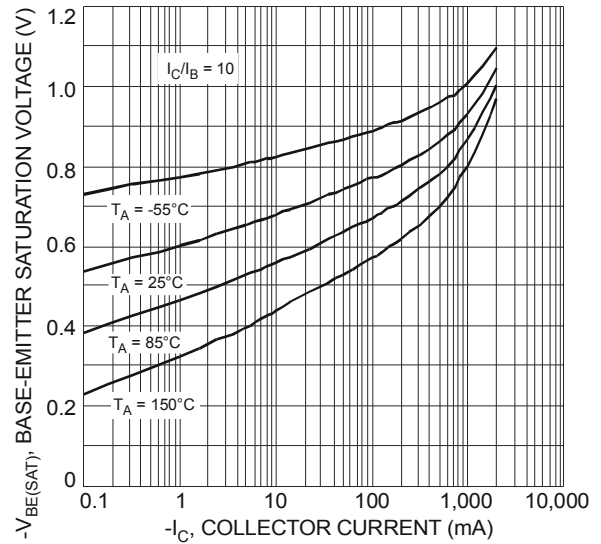


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

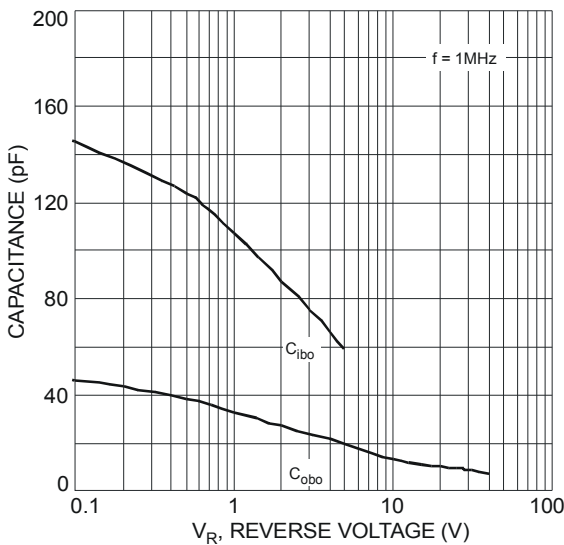


Fig. 7 Typical Capacitance Characteristics



DSS5240V

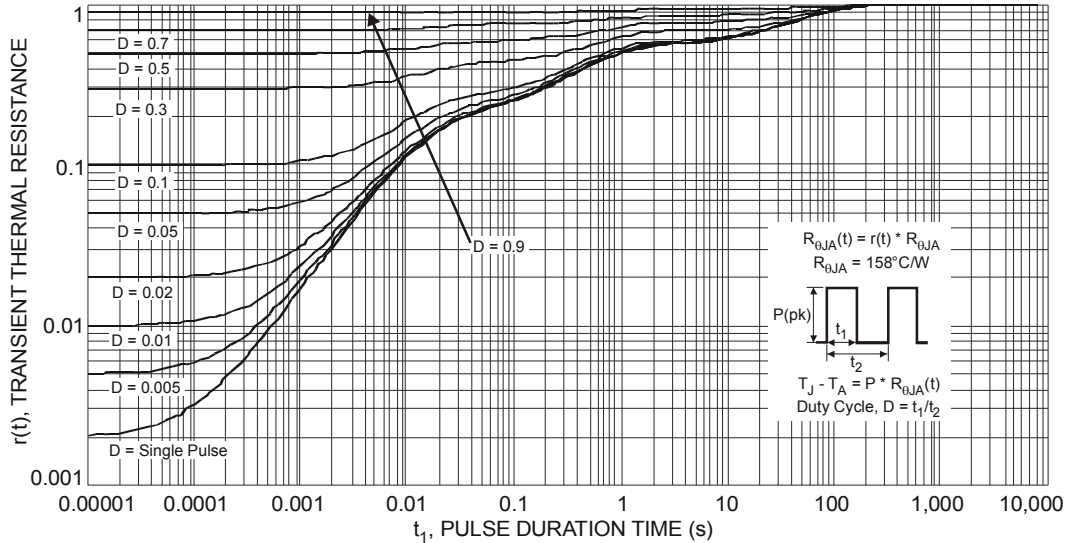


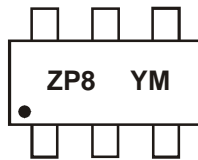
Fig. 8 Transient Thermal Response (Note 4)

**Ordering Information** (Note 6)

<b>Part Number</b> DSS5240V-7	<b>Case</b> SOT-563	<b>Packaging</b> 3000/Tape & Reel
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Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

**Marking Information**

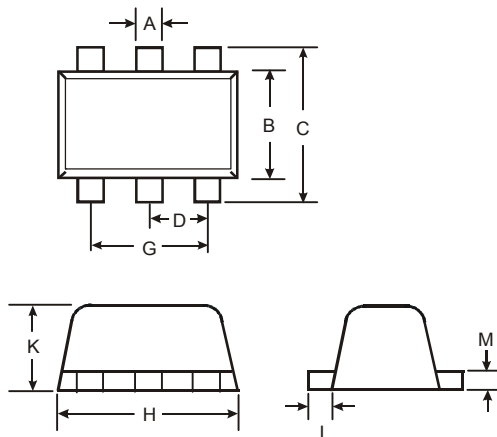


ZP8 = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year (ex: V = 2008)  
 M = Month (ex: 9 = September)

Date Code Key

<b>Year</b>	2008	2009	2010	2011	2012	2013	2014	2015				
<b>Code</b>	V	W	X	Y	Z	A	B	C				
<b>Month</b>	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
<b>Code</b>	1	2	3	4	5	6	7	8	9	O	N	D

**Package Outline Dimensions**

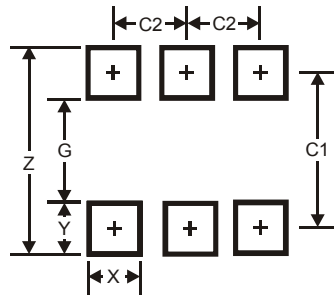


SOT-563			
Dim	Min	Max	Typ
A	0.15	0.30	0.20
B	1.10	1.25	1.20
C	1.55	1.70	1.60
D	-	-	0.50
G	0.90	1.10	1.00
H	1.50	1.70	1.60
K	0.55	0.60	0.60
L	0.10	0.30	0.20
M	0.10	0.18	0.11

All Dimensions in mm

NEW PRODUCT

## Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.2
G	1.2
X	0.375
Y	0.5
C1	1.7
C2	0.5

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